



PDTD123EK,115 Information

Part Number PDTD123EK,115

Manufacturer NXP

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

Description TRANS PREBIAS NPN 250MW SMT3

Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









PDTD123EK,115 Specifications

	Report errors?
Supplier Device Package	SMT3; MPAK
Package / Case	TO-236-3, SC-59, SOT-23-3
Mounting Type	Surface Mount
Power - Max	250mW
Frequency - Transition	-
Current - Collector Cutoff (Max)	500nA
Vce Saturation (Max) @ Ib, Ic	300mV @ 2.5mA, 50mA
DC Current Gain (hFE) (Min) @ Ic, Vce	40 @ 50mA, 5V
Resistor - Emitter Base (R2) (Ohms)	2.2k
Resistor - Base (R1) (Ohms)	2.2k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	500mA
Transistor Type	NPN - Pre-Biased
Series	-
Package	TO-236-3, SC-59, SOT-23-3
	Transistors - Bipolar (BJT) - Single, Pre-Biased
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Manufacturer Part Number	PDTD123EK,115

PDTD123EK,115 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

PDTD123EK,115 Payment Methods



















PDTD123EK,115 Shipping Methods













If you have any question about PDTD123EK,115, please do not hesitate to contact us!

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